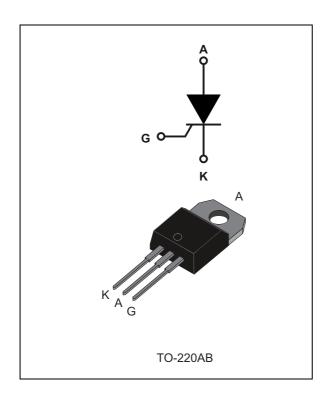
TN2015H-6T



High temperature 20 A SCRs

Datasheet - production data



Description

Thanks to a junction temperature T_j up to 150 °C and a non-isolated TO-220 package, the TN2015H-6T offers high thermal performance up to 20 A rms.

The trade-off between the device's noise immunity (dV/dt = 750 V/ μ s), its gate triggering current (I_{GT} = 15 mA) and its turn-on current rise (dI/dt = 100 A/ μ s) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances, and inrush current limiting circuits.

Table 1. Device summary

| Order code | Package | V _{DRM} /V _{RRM} | I _{GT} |
|------------|----------|------------------------------------|-----------------|
| TN2015H-6T | TO-220AB | 600 V | 15 mA |

Features

- High junction temperature: T_i = 150 °C
- High noise immunity dV/dt = 750 V/μs up to 150 °C
- Gate triggering current I_{GT} = 15 mA
- Blocking voltage V_{DRM}/V_{RRM} = 600 V
- High turn on current rise dl/dt: 100 A/µs
- ECOPACK[®]2 compliant component

Applications

- Voltage regulator circuits for motorbikes
- · Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

Characteristics TN2015H-6T

1 Characteristics

Table 2. Absolute ratings

| Symbol | Parameter | | | Value | Unit | |
|----------------------------------------|----------------------------------------------------------------------------------------------------------------------|-------------------------|-------------------------|--------------------------------|------|--|
| I _{T(RMS)} | On-state rms current (180° conduction a | T _c = 132 °C | 20 | Α | | |
| | | T _C = 132 °C | 12.7 | | | |
| I _{T(AV)} | Average on-state current (180° conduction angle) | | T _c = 137 °C | 10 | Α | |
| | | | T _c = 140 °C | 8 | | |
| l | Non repetitive surge peak on-state curre | nt | t = 8.3 ms | 197 | Α | |
| ITSM | (T _j initial = 25 °C) | | t = 10 ms | 180 | ^ | |
| l ² t | I^2 t value for fusing (T_j initial = 25 °C) | $t_p = 10 \text{ ms}$ | 162 | A ² s | | |
| dl/dt | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$, $T_j = 25 \text{ °C}$ | 100 | A/µs | | | |
| V _{DRM} , V _{RRM} | Repetitive peak off-state voltage | | | 600 | V | |
| I_{GM} | Peak gate current $t_p = 20 \mu s$ | | T _j = 150 °C | 4 | Α | |
| P _{G(AV)} | Average gate power dissipation | 1 | V | | | |
| T _{stg} T _j | Storage junction temperature range Operating junction temperature range | | | - 40 to + 150 - 40 to + 150 | °C | |
| T _L | Maximum lead temperature for soldering during 10 s | | | 260 | ç | |

Table 3. Electrical characteristics ($T_j = 25$ °C, unless otherwise specified)

| Symbol | Test conditions | | | Value | Unit |
|-----------------|---------------------------------------------------------------------------------------------------------------------------------------------------------|--|------|-------|------|
| 1 | $V_D = 12 \text{ V, R}_L = 33 \Omega$ | | Тур. | 6 | mA |
| I _{GT} | VD = 12 V, IVL = 33 22 | | Max. | 15 | |
| V_{GT} | $V_D = 12 \text{ V}, R_L = 33 \Omega$ | | Max. | 1.3 | V |
| V _{GD} | $V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$ | | Min. | 0.2 | V |
| I _H | I _T = 500 mA, gate open | | | 50 | mA |
| ΙL | $I_{G} = 1.2 \times I_{GT}$ | | Max. | 60 | mA |
| dV/dt | $V_D = 402 \text{ V, gate open}$ $T_j = 150 \text{ °C}$ | | Min. | 750 | V/µs |
| t _{gt} | $I_T = 40 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA},$ $(dI_G/dt) \text{max} = 0.2 \text{ A/}\mu\text{s}$ | | Тур | 1.9 | μs |
| t _q | $V_D = 402 \text{ V}, V_R = 25 \text{ V}, I_T = 20 \text{ A}, \\ (dI_G/dt)max = 30A/\mu s, dV_D/dt = 50 \text{ V}/\mu s $ $T_j = 150 ^{\circ}\text{C}$ | | Тур | 70 | μs |

TN2015H-6T Characteristics

Table 4. Static characteristics

| Symbol | Test conditions | | | Value | Unit |
|--------------------|-------------------------------------------------|-------------------------|--------|-------|------|
| V_{TM} | $I_{TM} = 40 \text{ A}, t_p = 380 \mu\text{s}$ | T _j = 25 °C | Max. | 1.6 | V |
| V _{t0} | Threshold voltage | T _j = 150 °C | Max. | 0.82 | V |
| R _d | Dynamic resistance | T _j = 150 °C | Max. | 17.5 | mΩ |
| I _{DRM} , | V - V - V | T _j = 25 °C | Max. | 5 | μΑ |
| I _{RRM} | $V_D = V_{DRM}, V_R = V_{RRM}$ | T _j = 150 °C | iviax. | 2 | mA |

Table 5. Thermal resistance

| Symbol | Parameter | Value | Unit |
|---------------|--------------------------|-------|------|
| $R_{th(j-c)}$ | Junction to case (AC) | 1.0 | °C/W |
| $R_{th(j-a)}$ | Junction to ambient (DC) | 60 | °C/W |

Figure 1. Maximum power dissipation versus average on-state current

20 P(W) α = 180°. DC. 18 α = 120° α = 90° 16 14 $\alpha = 30$ 12 10 8 6 4 2 $I_{\mathsf{T}(\mathsf{AV})}(\mathsf{A})$ 15 10

Figure 2. Average and DC on-state current versus case temperature

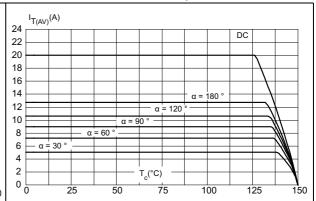
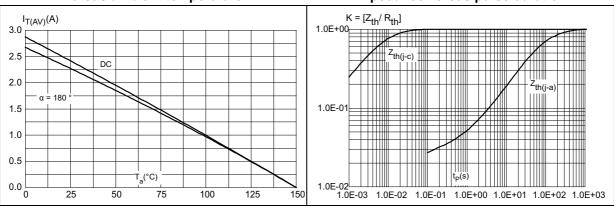


Figure 3. Average and DC on-state current versus ambient temperature

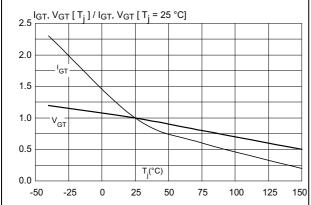
Figure 4. Relative variation of thermal impedance versus pulse duration



Characteristics TN2015H-6T

Figure 5. Relative variation of gate triggering current and gate voltage versus junction temperature (typical values)

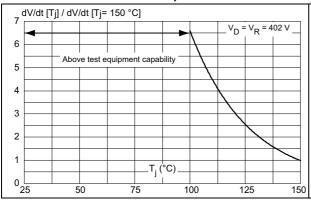
Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)



2.5 2.0 1.5 1.0 0.5 0.0 -50 -25 0 25 50 75 100 125 150

Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

Figure 8. Surge peak on-state current versus number of cycles



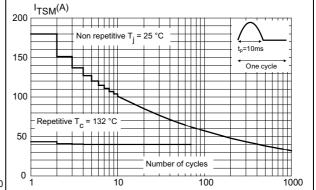
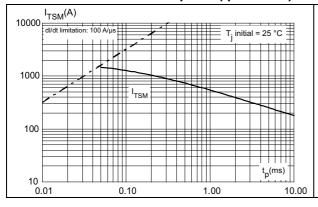
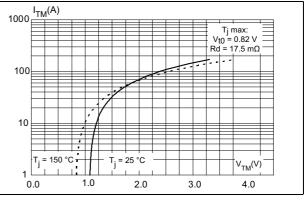


Figure 9. Non-repetitive surge peak on-state current for a sinusoidal pulse (tp < 10 ms)

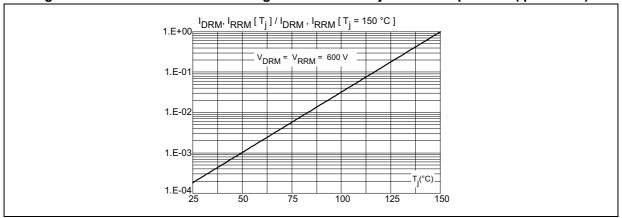
Figure 10. On-state characteristics (maximum values)





TN2015H-6T Characteristics

Figure 11. Relative variation of leakage current versus junction temperature (tp < 10 ms)



Package information TN2015H-6T

2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Halogen free molding compound
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

B Ø I b2 F F A A I2 C2 M C1

Figure 12. TO-220AB dimension definitions

TN2015H-6T Package information

Table 6. TO-220AB dimension values

| | Dimensions | | | | | | |
|------|------------|-------------|-------|-------|--------|-------|--|
| Ref. | | Millimeters | | | Inches | | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. | |
| А | 15.20 | | 15.90 | 0.598 | | 0.625 | |
| a1 | | 3.75 | | | 0.147 | | |
| a2 | 13.00 | | 14.00 | 0.511 | | 0.551 | |
| В | 10.00 | | 10.40 | 0.393 | | 0.409 | |
| b1 | 0.61 | | 0.88 | 0.024 | | 0.034 | |
| b2 | 1.23 | | 1.32 | 0.048 | | 0.051 | |
| С | 4.40 | | 4.60 | 0.173 | | 0.181 | |
| c1 | 0.49 | | 0.70 | 0.019 | | 0.027 | |
| c2 | 2.40 | | 2.72 | 0.094 | | 0.107 | |
| е | 2.40 | | 2.70 | 0.094 | | 0.106 | |
| F | 6.20 | | 6.60 | 0.244 | | 0.259 | |
| ØI | 3.75 | | 3.85 | 0.147 | | 0.151 | |
| 14 | 15.80 | 16.40 | 16.80 | 0.622 | 0.646 | 0.661 | |
| L | 2.65 | | 2.95 | 0.104 | | 0.116 | |
| l2 | 1.14 | | 1.70 | 0.044 | | 0.066 | |
| 13 | 1.14 | | 1.70 | 0.044 | | 0.066 | |
| М | | 2.60 | | | 0.102 | | |

Ordering information TN2015H-6T

3 Ordering information

Figure 13. Ordering information scheme

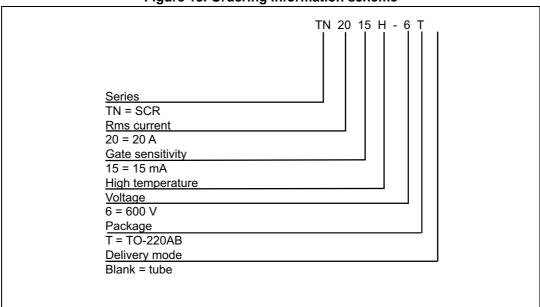


Table 7. Ordering information

| Order code | Marking | Package | Weight | Base qty | Delivery mode |
|------------|----------|----------|--------|----------|---------------|
| TN2015H-6T | TN2015H6 | TO-220AB | 2.3 g | 50 | Tube |

4 Revision history

Table 8. Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 25-Feb-2015 | 1 | Initial release. |

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